SAMYANG ELECTRONICS *MURF620CT --- MURF660CT*

SUPER FAST RECTIFIERS

VOLTAGE RANGE: 200 --- 600 V
CURRENT: 6.0A

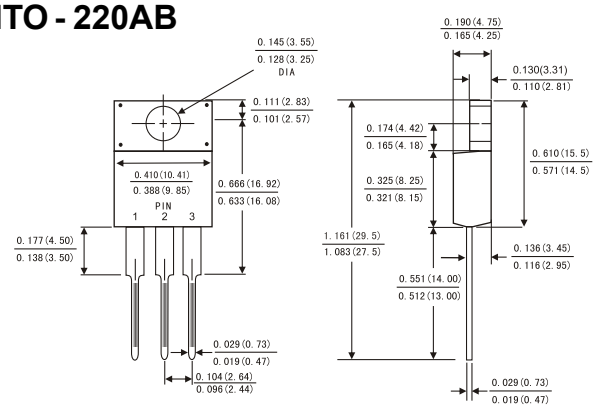
FEATURES

- ◇Metal-semiconductor junction with guard ring
- ◇Epitaxial construction
- ◇Low forward voltage drop,low switching losses
- ◇High surge capability
- ◇For use in low voltage,high frequency inverters free wheeling,and polarity protection applications
- ◇The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇Case:JEDEC ITO-220AB,molded plastic
- ◇Terminals: Axial lead ,solderable per MIL- STD-750,Method 2026
- ◇Polarity: As marked
- ◇Weight: 0.08ounces,2.24 grams
- ◇Mounting position: Any

ITO - 220AB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		Symbols	MURF 620CT	MURF 640CT	MURF 660CT	Units
Maximum repetitive peak reverse voltage		V_{RRM}	200	400	600	Volts
Maximum RMS voltage		V_{RMS}	140	280	420	Volts
Maximum DC blocking voltage		V_{DC}	200	400	600	Volts
Maximum average forward rectified current(see Fig.1)	Per leg	$I_{(AV)}$	3.0			Amps
	Total device		6.0			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		I_{FSM}	75			Amps
Maximum instantaneous forward voltage at 10.0 A(Note 1)		V_F	0.975	1.3	1.7	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T_A =25℃	I_R	5	10		uA
	T_A =125℃		500			
Maximum Reverse Recovery Time (Note 2)		Trr	35			ns
Typical thermal resistance (Note 3)		$R_{\theta JC}$	3.0			℃/W
Operating junction temperature range		T_J	-65 to+150			℃
Storage temperature range		T_{STG}	-65 to+150			℃

NOTE: 1. Pulse test:300us pulse width,1% duty cycle.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3.Thermal resistance junction to ambient

www.diode.co.kr

FIG.1-FORWARD CURRENT DERATING CURVE

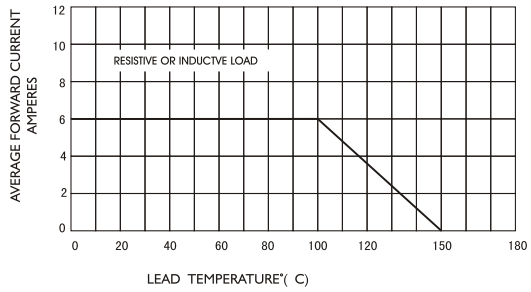


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

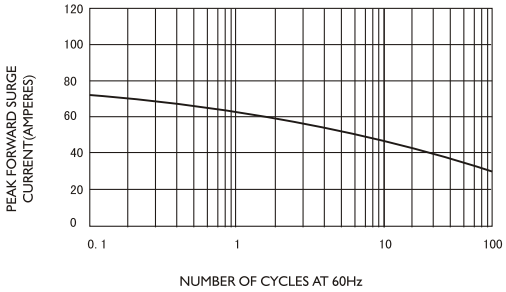


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

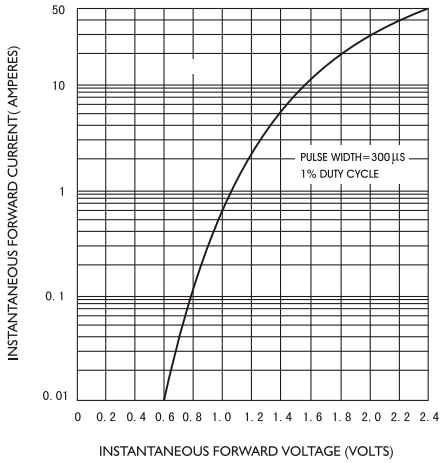


FIG.4-TYPICAL REVERSE CHARACTERISTICS

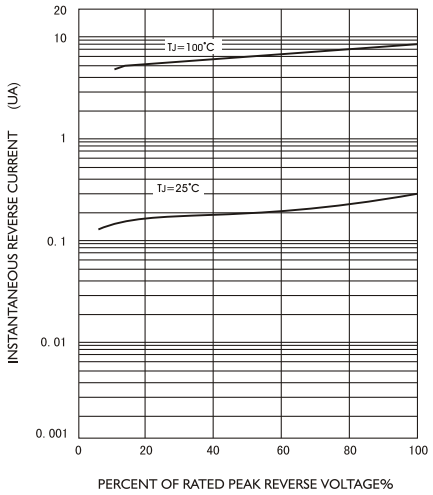


FIG.5-TYPICAL JUNCTION CAPACITANCE

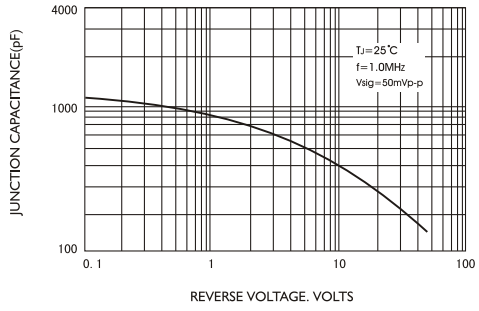


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

